

Magnetic properties of the noncentrosymmetric tetragonal antiferromagnet EuPtSi₃

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We report a comprehensive study of single crystals of the noncentrosymmetric rare-earth compound EuPtSi₃ grown by the optical floating-zone technique. Measurements of the magnetization, ac susceptibility, and specific heat consistently establish antiferromagnetic order of localized Eu²⁺ moments below the Néel temperature $T_N = 17$ K, followed by a second magnetic transition at $T_{N1} = 16$ K. For a magnetic field along the easy [001] axis, the magnetic phase diagram is composed of these two phases. For fields applied in the magnetically hard basal plane, two additional phases emerge under magnetic field, where the in-plane anisotropy is weak with [100] being the hardest axis. At the phase transitions, the magnetic properties exhibit hysteresis and discrepancies between differential and ac susceptibility, suggesting slow reorientation processes of mesoscale magnetic textures. Consistently, powder and single-crystal neutron diffraction in zero field identify magnetic textures that are modulated on a length scale of the order of 100 Å, most likely in the form of Néel-type antiferromagnetic cycloids.

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I. MOTIVATION

In rare-earth intermetallic compounds the interplay of localized moments with itinerant electrons may give rise to a plethora of phenomena including complex forms of magnetic order [1–3], quantum critical behavior [4–6], and unconventional superconductivity [7–9]. While cerium-based compounds are most commonly studied, due to the comparably simple electronic configuration of Ce³⁺ with a single 4*f* electron, europium-based compounds offer an intriguing alternative. For europium, the oxidation state Eu²⁺ is rather stable due to the electron configuration 4*f*⁷ with a half-filled *f* shell, resulting in a quenched orbital momentum and very weak spin-orbit coupling for a rare-earth compound. In combination with crystal structures lacking inversion symmetry, in which Dzyaloshinskii-Moriya interactions potentially are leading order in spin-orbit coupling [10–12], long-wavelength modulated states may emerge in

europium-based compounds in analogy to transition-metal compounds [13–18].

A candidate for such behavior is EuPtSi₃, belonging to a class of europium-based compounds crystallizing in the noncentrosymmetric tetragonal space group *I4mm* [19–32]. In a seminal study, Kumar and colleagues investigated single-crystal platelets grown from a tin solution [33]. Despite superconducting inclusions of the solvent obscuring the intrinsic low-temperature transport properties, the authors established that magnetism in EuPtSi₃ is carried by local Eu²⁺ moments and that [001] is the direction of the magnetic easy axis. Signatures at 17 K and 16 K were attributed to two subsequent phase transitions. Analyzing the size of the specific heat anomaly and ¹⁵¹Eu Mössbauer spectra, the authors concluded that as a function of decreasing temperatures a paramagnetic state, an incommensurate amplitude-modulated antiferromagnetic state, and a commensurate equal-moment antiferromagnetic state are observed. Electronic structure calculations accounted for the easy axis and the size of the magnetic moments, suggesting that the magnetic structure of EuPtSi₃ is incommensurate or noncollinear [34]. So far, however, the available data were scarce, in particular for fields in the basal plane, and microscopic information on the magnetic structure was lacking. Moreover, aspects such as the in-plane anisotropy or the dependence of the magnetic properties on the temperature and field history have not been addressed.

The present study reports the growth of a phase-pure single crystal of EuPtSi₃ by means of the optical floating-zone

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technique, thus avoiding the issues associated with high-temperature solution growth. Magnetic phase diagrams for the major crystallographic axes are inferred from comprehensive measurements of the magnetization, ac susceptibility, and specific heat. For magnetic field parallel to the easy [001] axis, two long-range ordered phases are observed. For magnetic fields applied in the hard basal plane, namely along [100] or [110], two additional phase pockets emerge at low temperature at elevated fields. The in-plane anisotropy is weak with [100] representing the hardest axis. Hysteresis as well as discrepancies between differential and ac susceptibility suggest the formation of complex mesoscale magnetic textures. Consistently, powder and single-crystal neutron diffraction in zero magnetic field indicate a long-wavelength modulation of local antiferromagnetic order, in contrast to Ref. [33].

II. EXPERIMENTAL METHODS

For our study, a single crystal of EuPtSi_3 was grown by means of the optical floating-zone technique using an ultrahigh vacuum compatible preparation chain [35]. This procedure contrasts previous studies of related compounds crystallizing in space group $I4mm$, in which polycrystalline specimens were typically prepared from the constituents by means of melting or sintering followed by an annealing process [20–22,36,37] or small single crystals were grown from high-temperature solutions using tin or indium as solvent [19,23,25,27,29,31,33]. While the growth from solution circumvents the challenges arising due to the high vapor pressure of europium efficiently, at least for EuPtSi_3 inclusions of the solvent result in a superconducting transition in electrical transport measurements, potentially masking the intrinsic low-temperature behavior [33].

Such inclusions of the solvent are avoided when growing single crystals from the melt as described in the following. Using our preparation chain as optimized for intermetallic compounds, all furnaces were pumped to ultrahigh vacuum prior to each step of the growth process, before an inert atmosphere was applied in the form of 6N argon additionally passed through a point-of-use gas purifier [35]. Since europium is highly reactive to oxygen and moisture at ambient conditions, as a first step in an argon glovebox stoichiometric amounts of high-purity europium (4N) [38] and platinum (4N) were weighed in for the synthesis of Eu_5Pt_4 [39]. Using a bespoke metal bellows load-lock, the elements were transferred into the horizontal cold boat furnace and melted by means of radio-frequency induction. Next, the resulting ingot, the additional platinum, and the silicon (6N) required for stoichiometric EuPtSi_3 were loaded into the rod casting furnace in which a polycrystalline feed rod with a diameter of 6 mm and a length of ~ 25 mm was cast, as shown in Fig. 1(a) [40].

In total, four such rods were prepared and used for two growth attempts in the image furnace [41]. The growth rates for the first and second attempt were 5 mm/h and 1 mm/h, respectively. In both cases, seed and feed rod were counter-rotating at 6 rpm under an inert argon atmosphere at a pressure of 5 bar. Despite evaporation losses, as observed by depositions on the inside of the image furnace presumably by the europium, stable growth conditions were obtained in both cases. The float-zoned ingots possess a shiny metallic surface

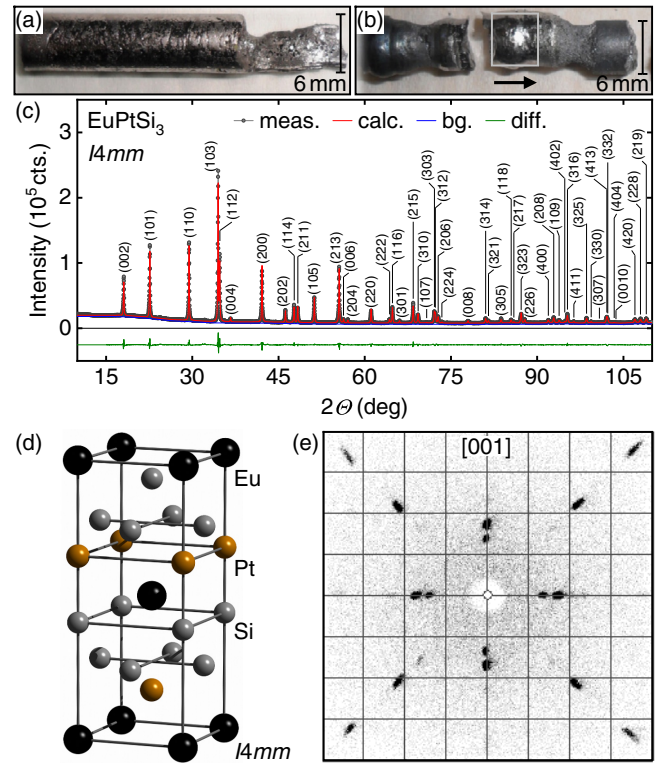


FIG. 1. Metallurgical analysis of EuPtSi_3 . (a) Polycrystalline feed rod. (b) Float-zoned ingot. The black arrow marks the growth direction. The central part yielding single-crystalline material is marked by the light gray box. (c) X-ray powder diffraction. Taking into account the background (bg.) of the setup, measured data (meas.) and a calculated Rietveld refinement (calc.) using the space group $I4mm$ are in excellent agreement. (d) Schematic depiction of the tetragonal unit cell. (e) X-ray Laue diffraction pattern from a single-crystal sample showing the fourfold symmetry of the [001] axis.

without visible oxidization, as depicted in Fig. 1(b) for the first growth.

The structural properties of powder prepared from the first float-zoned ingot were studied on a STOE STADI P X-ray diffractometer with copper $K_{\alpha 1}$ radiation. As shown in Fig. 1(c), the measured diffractogram is in excellent agreement with phase-pure EuPtSi_3 crystallizing in the noncentrosymmetric tetragonal BaNiSn_3 -type structure with space group $I4mm$. A Rietveld refinement with site occupancies fixed to their nominal values yields lattice constants $a = 4.286 \text{ \AA}$ and $c = 9.795 \text{ \AA}$, as summarized in Table I. These values are in acceptable agreement with those reported by Kumar and colleagues ($a = 4.2660 \text{ \AA}$, $c = 9.8768 \text{ \AA}$), where discrepancies may hint toward the incorporation of tin into the structure in Ref. [33]. The crystal structure of EuPtSi_3 is illustrated in Fig. 1(d), visualizing the breaking of inversion symmetry due to the distinct stacking order of the platinum and silicon layers.

Using x-ray Laue diffraction, a large single-crystal grain of a few millimeters in all dimensions was identified in the float-zoned ingot from the first growth attempt, where Fig. 1(e) shows a typical Laue pattern of the fourfold [001] axis. The second growth attempt using the slower growth rate did not

TABLE I. Structural parameters of EuPtSi_3 crystallizing in the tetragonal BaNiSn_3 -type structure with space group $I4mm$ (No. 107). The structural data were modeled for Eu1, Pt1, Si1 occupying $2a$ sites $[0, 0, z]$, and Si2 occupying $4b$ sites $[0, 1/2, z]$ with Eu1 being fixed to the origin $z = 0$. Data from neutron and x-ray diffraction are in excellent agreement. Numbers in parentheses give statistical deviations of the last significant digit.

Atomic site, Wyckoff position	Neutron, $T = 300$ K $a = 4.2832(4)$ Å, $c = 9.7932(7)$ Å				X-ray, $T = 297$ K $a = 4.28552(2)$ Å, $c = 9.79466(6)$ Å				Neutron, $T = 3.8$ K $a = 4.2718(3)$ Å, $c = 9.7747(8)$ Å			
	x/a	y/a	z/c	$B_{\text{iso}}(\text{Å})^2$	x/a	y/a	z/c	$B_{\text{iso}}(\text{Å})^2$	x/a	y/a	z/c	$B_{\text{iso}}(\text{Å})^2$
Eu1, $2a$	0	0	0	1.4(2)	0	0	0	1.98(6)	0	0	0	1.4(2)
Pt1, $2a$	0	0	0.646(1)	1.1(1)	0	0	0.6475(2)	1.14(3)	0	0	0.646(1)	0.9(1)
Si1, $2a$	0	0	0.402(2)	2.3(4)	0	0	0.4009(8)	2.4(2)	0	0	0.398(2)	2.2(3)
Si2, $4b$	0	1/2	0.262(2)	1.2(2)	0	1/2	0.2583(5)	1.3(1)	0	1/2	0.259(2)	1.4(1)

yield single-crystalline sections of the ingot. A cube with an edge length of 2 mm and surfaces perpendicular to $[001]$, $[110]$, and $[1\bar{1}0]$ was cut from the single-crystal grain using a wire saw. Measurements of the bulk properties were carried out in a Quantum Design physical property measurement system. The magnetization was measured with the standard extraction technique of the ACMS-II option. The ac susceptibility was measured with an excitation frequency of 911 Hz at an excitation amplitude of 1 mT. The specific heat was measured using a quasiadiabatic large heat pulse technique, where typical pulses had a size of 30% of the temperature at the start of the pulse [42].

The magnetic structure of EuPtSi_3 was studied using the high-resolution powder diffractometer SPODI [43,44] and the 4-circle single-crystal diffractometer HEiDi [45], both at the Heinz Maier-Leibnitz Zentrum (MLZ). On SPODI, measurements were carried out in Debye-Scherrer geometry at an incident neutron wavelength of 1.55 Å. The sample consisted of ground float-zoned material with a grain size of less than 20 μm . Due to the high absorption cross section of europium, the powder was filled into a gap of 0.5 mm width between the walls of a hollow cylinder made of aluminum with a wall thickness of 0.2 mm and an outer diameter of 20 mm. The cylinder was mounted into a top-loading closed-cycle cryostat using helium as exchange gas. Diffraction data were collected between 3.8 K and 300 K and corrected for geometrical aberrations and the curvature of the Debye-Scherrer rings.

Full-profile Rietveld refinements of the diffraction data were carried out using pseudo-Voigt peak profiles in the FullProf program package [46]. The background contribution was determined in terms of a linear interpolation of selected data points in nonoverlapping regions. The following parameters were varied during the fitting: scale factor, zero-angular shift, profile shape parameters, resolution (Caglioti) parameters, asymmetry and lattice parameters, as well as fractional coordinates of atoms and their displacement parameters. Since the site occupations deviated only slightly during fitting, they were fixed to their nominal values in order to suppress correlations with the displacement parameters.

On HEiDi, the single-crystal cube used for the measurements of the bulk properties was studied by means of neutrons at an incident wavelength of 1.17 Å. While cold neutrons would be favorable in terms of high resolution at small scattering angles, the absorption cross section of europium requires the use of faster neutrons in order to achieve sufficient intensity. Rocking scans on various reflections revealed

Gaussian profiles with a full width at half maximum just above the experimental resolution of $\sim 0.3^\circ$, confirming the single-crystalline nature and high crystalline quality of the sample with a small mosaic spread of about 0.2° . Using a closed-cycle cryostat, a set of specific reflections was studied in the temperature range between 2 K and 20 K. Owing to the high absorption of the sample, the limited coverage of reciprocal space does not allow for a structure refinement.

As the magnetic properties of EuPtSi_3 depend on the temperature and field history, the following measurement protocols are distinguished. For data as a function of temperature, only one protocol was used. Prior to each measurement, the sample was cooled to 2 K from high temperatures well above T_N in zero magnetic field at a rate of about 5 K/min. Next, the desired field value was applied before magnetization and ac susceptibility data were collected alternately while increasing the sample temperature at a rate of 0.3 K/min. For temperatures above 30 K, the rate was increased to 1 K/min. This protocol is referred to as zero-field cooling (zfc).

For data as a function of field, the sample was first cooled from high temperatures well above T_N to the desired temperature in zero magnetic field. In the subsequent field cycle, the field was changed in steps of typically 100 mT. At each field value, the magnetization and subsequently the ac susceptibility were measured, before the next field value was approached at a rate of 10 mT/s. Five branches are distinguished: (i) $0 \text{ T} \rightarrow +14 \text{ T}$, (ii) $+14 \text{ T} \rightarrow 0 \text{ T}$, (iii) $0 \text{ T} \rightarrow -14 \text{ T}$, (ii*) $-14 \text{ T} \rightarrow 0 \text{ T}$, and (iii*) $0 \text{ T} \rightarrow +14 \text{ T}$. Branch (i) corresponds to the situation after zero-field cooling for data as a function of temperature. Branches (ii) and (ii*) are measured under decreasing absolute field values starting in high fields. Branches (iii) and (iii*) are measured under increasing absolute field values starting from zero field, but coming from the field-polarized state in the opposite field direction. This equivalence has been checked for several temperatures (not shown).

Representing a key result of our study, magnetic phase diagrams are inferred for fields applied along $[001]$, $[100]$, and $[110]$. In measurements as a function of magnetic field, up to four signatures are observed and labeled in increasing field strength H_1 , H_2 , H_3 , and H_4 . Signatures in measurements as a function of temperature are labeled T_1 , T_2 , T_3 , and T_4 . For clarity, transition fields and temperatures are denoted with the same number when belonging to the same transition line in the phase diagram. Furthermore, the transition temperatures observed in zero magnetic field, $T_{N1} = 16 \text{ K}$ and $T_N = 17 \text{ K}$,

correspond to the origin points of the transition lines (1) and (4), namely $T_{N1} = T_1(H = 0)$ and $T_N = T_4(H = 0)$ [47]. In fact, the positions of the transitions in phase space depend not only on the temperature and magnetic field strength, but also on the field direction. For convenience, these dependencies are omitted in the nomenclature. Although this naming scheme may lead to peculiarities when considering single measurements only, it proves to be intuitive when taking into account the magnetic phase diagrams as a whole.

III. EXPERIMENTAL RESULTS

The presentation of the experimental results starts in Sec. III A with the zero-field susceptibility and an account of the anisotropy of the magnetization at low temperatures. Next, for field parallel to [001], in Sec. III B magnetization and susceptibility are shown as a function of field and temperature, complemented by the specific heat and the magnetic contribution to the entropy. Following the same organizational structure, in Sec. III C magnetization and susceptibility as a function of field and temperature are shown for fields parallel to [100] and [110]. As one of the key results of this study, in Sec. III D magnetic phase diagrams are presented for the three major crystallographic directions. In Sec. III E the results of the powder and single-crystal neutron diffraction experiments are delineated, before the magnetic structure is discussed in Sec. III F.

A. Magnetic key characteristics and anisotropies

Shown in Fig. 2(a) is the temperature dependence of the ac susceptibility for excitation fields parallel to the major crystallographic axes [100], [110], and [001]. As a function of decreasing temperature, a Curie-Weiss-like increase of the susceptibility is observed until a distinct maximum at $T_N = 17$ K marks the onset of magnetic order. The ac susceptibility curves for excitation fields applied within the tetragonal basal plane, namely [100] (red symbols) and [110] (orange symbols), are almost identical and their absolute values are lower than for excitation fields along [001] (blue symbols). The crossing of the curves below T_N is associated with the complex magnetic properties of EuPtSi₃, as will become clear further below.

The behavior in the paramagnetic state above T_N may be analyzed in terms of the temperature dependence of the inverse ac susceptibility, shown in Fig. 2(b). Excellent agreement between the measured data and linear Curie-Weiss fits (solid lines) is observed up to room temperature. From the slope of these fits, fluctuating moments of $\mu_{\text{eff}} = (7.8 \pm 0.1) \mu_B \text{ f.u.}^{-1}$ are inferred for all three directions, consistent with the free-ion value of Eu²⁺, $\mu_{\text{eff}} = 7.9 \mu_B \text{ f.u.}^{-1}$. Curie-Weiss temperatures of (4.1 ± 0.6) K, (4.2 ± 0.5) K, and (9.7 ± 0.9) K are inferred for excitation fields along [100], [110], and [001], consistent with Ref. [33]. These values are positive and distinctly smaller than T_N , contrasting the expectations for both simple antiferromagnetism and ferromagnetism. Furthermore, as shown in the inset of Fig. 2(b), the measured susceptibility starts to deviate from the linear fits already well above T_N . In combination with the neutron scattering data indicating a long-wavelength modulation of

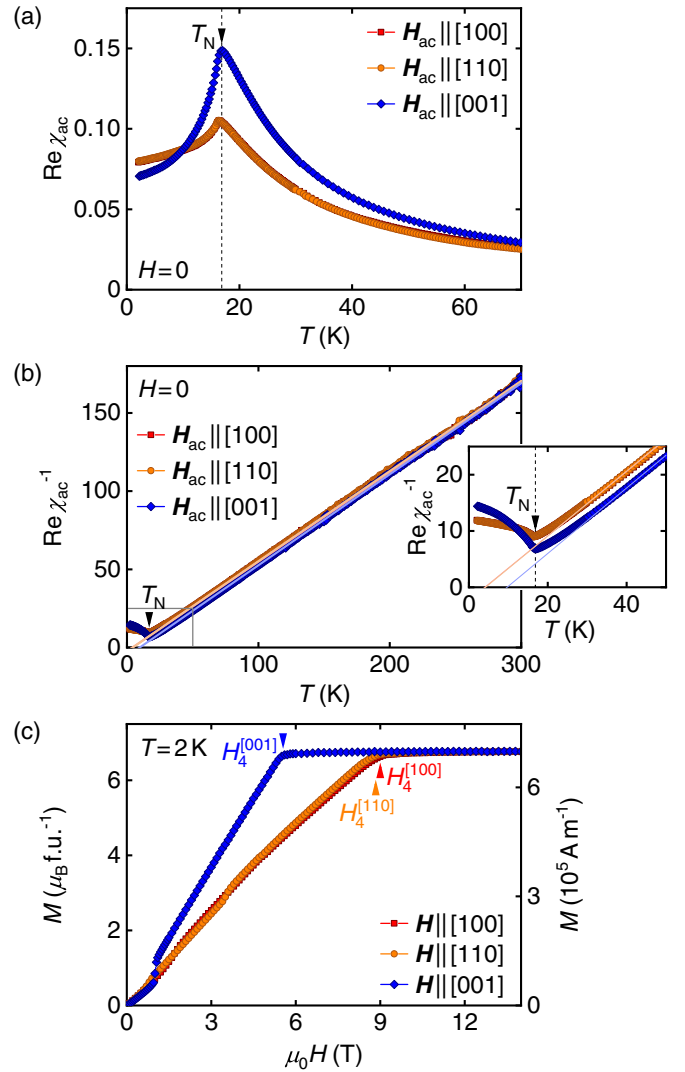


FIG. 2. Magnetic properties of EuPtSi₃. (a) Temperature dependence of the ac susceptibility in zero static field for excitation fields along the major crystallographic directions. (b) Inverse susceptibility as a function of temperature. The solid lines are linear fits indicating Curie-Weiss-like behavior. Inset: Close-up view of low temperatures. (c) Magnetization as a function of increasing field after initial zero-field cooling at low temperature.

the magnetic structure, these observations imply that contributions beyond simple exchange interactions, for instance in the form of Dzyaloshinskii-Moriya interactions, are essential for the description of the magnetic properties of EuPtSi₃ already on the mean-field level.

The field dependence of the magnetization at low temperatures, shown in Fig. 2(c), provides further insight into the general character of the magnetism in EuPtSi₃. As a function of increasing field, the magnetization increases monotonically until kinks, referred to as H_4 , mark the onset of the field-polarized state. At 2 K, value of $\mu_0 H_4^{[100]} = 9.0$ T, $\mu_0 H_4^{[110]} = 8.8$ T, and $\mu_0 H_4^{[001]} = 5.5$ T are obtained for fields applied parallel to the major crystallographic axes. In agreement with the ac susceptibility, these values indicate an easy [001] axis and a hard basal plane with a small but finite in-

plane anisotropy and [100] as the hardest axis. At high fields, the magnetization essentially saturates at $\mu_s = 6.8 \mu_B \text{ f.u.}^{-1}$ independent of the crystallographic direction, consistent with the free-ion value of Eu^{2+} , $\mu_s = 7 \mu_B \text{ f.u.}^{-1}$. The good agreement of both μ_{eff} and μ_s with their respective free-ion values indicates that the magnetism in EuPtSi_3 is described well in terms of localized Eu^{2+} moments. These observations stand in contrast to the reduced values reported in Ref. [33], which were attributed to up to 8% of tin inclusions in the sample. At fields below H_4 , changes of slope in the magnetization are characteristic of phase transitions of the magnetic order as addressed in the following.

B. Properties for field along the easy [001] axis

For magnetic field along the easy [001] axis, as shown in Fig. 3(a), the susceptibility as a function of field at low temperature exhibits three regimes of essentially constant values. Starting at zero field with a value of 0.07, a distinct maximum at 1.0 T, referred to as H_1 , is followed by a plateau at a susceptibility value of 0.16. Under further increasing field, a point of inflection at 5.5 T defines the transition to the field-polarized state, referred to as H_4 . At high fields, the susceptibility exhibits a vanishingly small value, reflecting the saturation of the magnetization as a key characteristic of local-moment magnetism.

The differential susceptibility calculated from the measured magnetization, dM/dH (open symbols), is tracked by the real part of the ac susceptibility, $\text{Re } \chi_{\text{ac}}$ (solid symbols), with exception of the transition regime around H_1 , where the maximum in dM/dH is more pronounced. Such discrepancies are abundant in materials with mesoscale magnetic textures and a characteristic of a very slow response of the system, suggesting that the transition at H_1 may involve the reorientation of large magnetic domains [48,49]. Consistent with this conjecture, different field histories, labeled (i) through (iii), result in very similar behavior with only minor changes of the shape of the anomaly at H_1 .

The evolution of H_1 and H_4 for increasing temperatures is illustrated in Figs. 3(b), 3(c), and 3(d), where the magnetization as well as the real and imaginary part of the ac susceptibility are shown for increasing fields after zero-field cooling. Most prominently, with increasing temperature both H_1 and H_4 shift to smaller field values and have vanished at 18 K. An upturn develops in the susceptibility just before the transition to the field-polarized regime that is, however, not associated with an additional phase transition. The imaginary part of the ac susceptibility, depicted in Fig. 3(d), is small and its field dependence tracks the real part qualitatively. Therefore, it can not be excluded that the imaginary part is due to a tiny phase shift well below 1 deg, which would imply that it represents an erroneous systematic contribution originating in the real part of the ac susceptibility. The putative offset of the absolute values, increasing with decreasing temperature, is due to eddy currents in the metallic sample and thus also not intrinsic.

As a function of temperature, the real part of the ac susceptibility exhibits up to two transitions, as shown in Fig. 4(a) for four field values with typical characteristics. Under decreasing temperature in zero magnetic field, the susceptibility shows

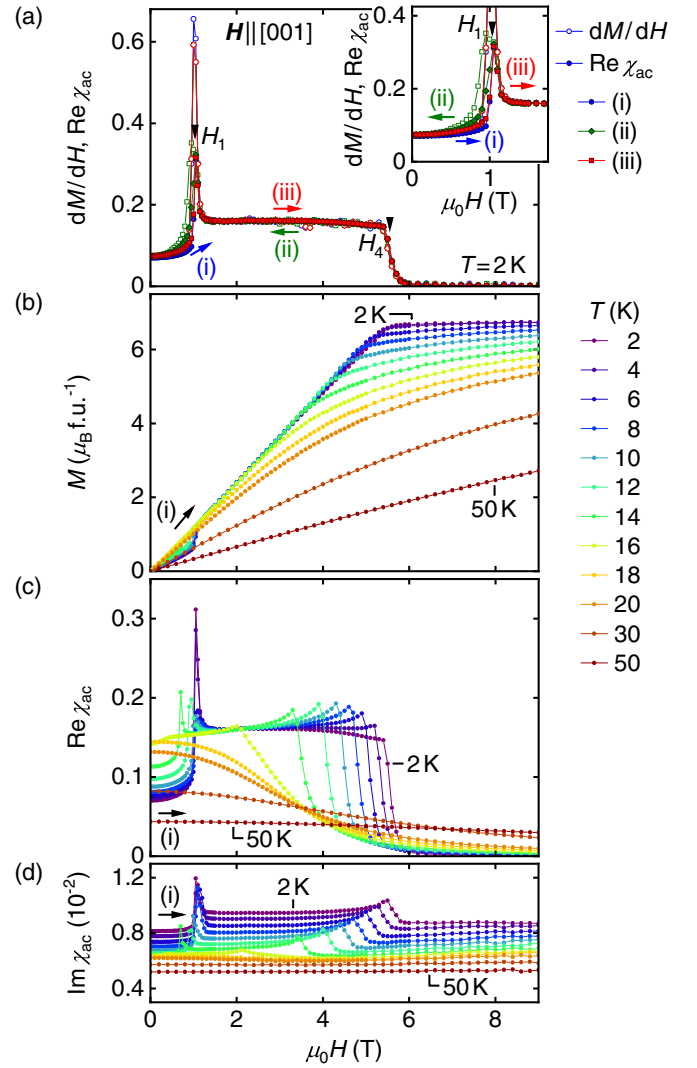


FIG. 3. Field dependence of the magnetic properties of EuPtSi_3 for field parallel to [001]. (a) Differential susceptibility calculated from the measured magnetization, dM/dH (open symbols), and real part of the ac susceptibility, $\text{Re } \chi_{\text{ac}}$ (solid symbols), at 2 K for different field histories. Inset: Enlarged view of the transition at low fields. [(b)–(d)] Magnetization as well as real and imaginary part of the ac susceptibility for different temperatures.

a Curie-Weiss-like dependence until a kink at T_4 marks the onset of long-range magnetic order. Below T_4 , the susceptibility is essentially constant until it decreases again below a second anomaly, marked T_1 . The zero-field values of the transition temperatures T_1 and T_4 are also referred to as $T_{N1} = T_1(H = 0)$ and $T_N = T_4(H = 0)$, respectively. The presence of two independent transitions is more pronounced in small applied fields. In a field of 1 T, the susceptibility exhibits a complex shape due to the weak temperature dependence of H_1 at low temperatures. For larger fields, only the kink at T_4 remains. The transition temperatures and fields inferred from the field and temperature dependence of the susceptibility are in excellent agreement.

The evolution of the magnetic properties for a large number of field values is illustrated in Figs. 4(b)–4(d). With increasing

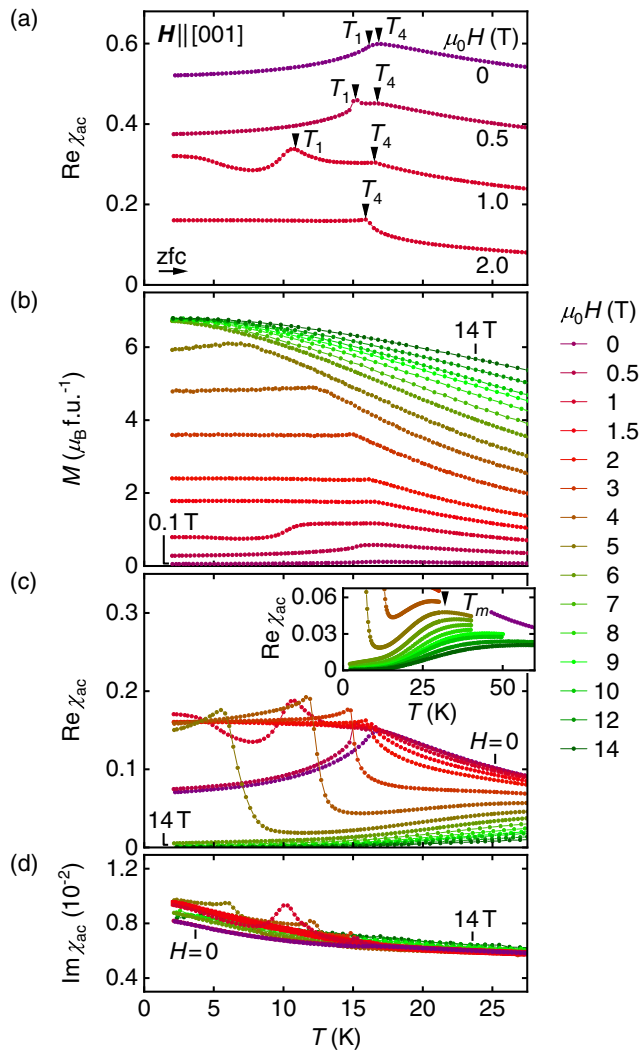


FIG. 4. Temperature dependence of the magnetic properties of EuPtSi₃ for field parallel to [001]. (a) Real part of the ac susceptibility for selected fields measured after zero-field cooling (zfc). Data are offset for clarity. [(b)–(d)] Magnetization as well as real and imaginary part of the ac susceptibility for a large number of fields up to 14 T. Inset: Real part of the ac susceptibility at high fields.

field, the transition at T_4 shifts to lower temperatures until having vanished at fields of 6 T and above. Additionally, as shown in the inset of Fig. 4(c), in high fields a shallow maximum in the real part of the susceptibility, referred to as T_m , is observed at temperatures well above T_N . The maximum shifts to higher temperatures with increasing field and marks the crossover between the field-polarized regime at low temperatures and high fields and the paramagnetic regime at high temperatures and low fields [50,51].

Further information on the nature of the phase transitions may be inferred from the specific heat, depicted in Fig. 5(a). In zero field, the specific heat at low temperature is dominated by a pronounced lambda anomaly at T_N , characteristic of a second-order phase transition. Closer inspection reveals that the anomaly exhibits fine structure in the form of two narrowly separated maxima. As highlighted in Fig. 5(b), under small applied fields along [001] the low-temperature maxi-

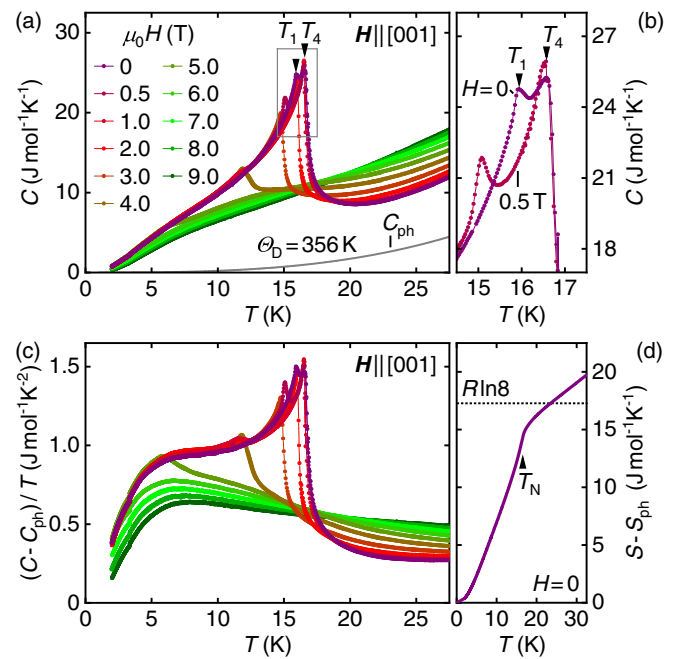


FIG. 5. Temperature dependence of the specific heat of EuPtSi₃ for field parallel to [001]. (a) Specific heat for different magnetic fields. The gray solid line indicates the phonon contribution, C_{ph} , using a Debye temperature $\Theta_D = 356$ K. (b) Close-up view of the transition regime. (c) Nonphonon contribution to the specific heat divided by temperature as a function of temperature. (d) Estimate of the entropy contribution not related to phonons.

mum distinctly shifts to lower temperatures and vanishes in fields exceeding 1 T, tracking T_1 as observed in the ac susceptibility. The high-temperature maximum associated with the lambda anomaly shifts to lower temperatures at higher fields and tracks T_4 . Thus, the transition at T_4 features a substantial reduction of the entropy characteristic of a second-order transition even under large magnetic fields. In contrast, the anomaly at T_1 exhibits a rather symmetric shape and is associated with a small change of entropy only, hinting toward a first-order character of the transition.

Plotting C/T as a function of T^2 (not shown) and fitting a straight line for $T > T_N$, we determine a Debye temperature $\Theta_D = 356$ K. The resulting phonon contribution with $C_{ph} \propto T^3$ describes the behavior at intermediate temperatures reasonably well. Consistent with the assumptions of the Debye model, the fit starts to deviate from the measured specific heat for high temperatures, $T > \Theta_D/10$, providing an excellent cross check as demonstrated in detail for MnSi and related compounds in Refs. [42,51]. When subtracting the phonon contribution from the measured data, the remaining specific heat may be attributed to electronic and magnetic excitations. This contribution divided by temperature $(C - C_{ph})/T$ is shown in Fig. 5(c).

For $T > T_N$, a constant value of $0.27 \text{ J mol}^{-1} \text{ K}^{-2}$ is observed in zero magnetic field. This contribution may be interpreted as electronic specific heat scaling linear in temperature with a relatively large Sommerfeld coefficient that is characteristic of heavy-fermion behavior. However, the slope at low temperatures suggests that $(C - C_{ph})/T$ may

become vanishingly small at temperatures well below 2 K. This discrepancy may hint toward an unusual breakdown of electronic correlations at low temperatures or the presence of additional effects at higher temperatures that cause a putative enhancement of the Sommerfeld coefficient. These additional complexities prevent us from separating electronic and magnetic contributions to the specific heat. Still, the numerical integration of $(C - C_{\text{ph}})/T$ as a function of temperature provides an estimate of the associated entropies, as shown for zero magnetic field in Fig. 5(d).

For Eu^{2+} , the quenched orbital momentum $L = 0$ implies a total momentum $J = S = 7/2$ corresponds to the spin momentum. Consequently, a total magnetic entropy $S_{\text{mag}} = R \ln 8$ is expected at high temperatures. Consistent with the results of Kumar and colleagues, who used a measurement on polycrystalline LaPtSi_3 for the subtraction of the phonon contribution, we obtain a value of $0.8R \ln 8$ around T_N . Possible explanations for this reduced value include magnetoelastic coupling, resulting in an overestimate of the phonon contribution, or magnetic correlations in the paramagnetic state above T_N . Also, the entropy contribution not related to phonons clearly exceeds $R \ln 8$ for temperatures well above T_N , which may be attributed to electronic excitations as described above.

In previous studies, information on the magnetic structure of EuPtSi_3 was inferred from the jump of the specific heat at the magnetic phase transition. Following these considerations, the size of the anomaly would allow to distinguish between a magnetic structure with moments of the same size on all sites (equal moment, EM) and moments of periodically varying size (amplitude modulated, AM) [33,52]. For $J = 7/2$, one expects $\Delta C_{\text{EM}} = (63/26)R = 20.15 \text{ J mol}^{-1} \text{ K}^{-1}$ and $\Delta C_{\text{AM}} = \frac{2}{3}C_{\text{EM}} = 13.43 \text{ J mol}^{-1} \text{ K}^{-1}$. Kumar and colleagues estimated $\Delta C = 14.6 \text{ J mol}^{-1} \text{ K}^{-1}$ and interpreted this value as a sign for an amplitude-modulated magnetic structure.

In this context, we note that the experimental value in Ref. [33] was larger than the calculated one, although tin inclusions may be expected to reduce the size of the specific heat anomaly in analogy to the magnetic moment in saturation. More importantly, however, the size of the jump as inferred from the specific heat just at T_N may be erroneous. Instead, the plateau well above the onset of magnetic order in $(C - C_{\text{ph}})/T$ provides a reliable point of reference, permitting us to determine the size of the jump unambiguously. In zero field, we find $\Delta C_{\text{el}}/T_c = (1.46 - 0.27) \text{ J mol}^{-1} \text{ K}^{-2}$ and $T_N = 17 \text{ K}$, translating to $\Delta C = 20.2 \text{ J mol}^{-1} \text{ K}^{-1}$. This value is in excellent agreement with a magnetic structure composed of equal moments.

C. Properties for fields in the hard basal plane

When applying the magnetic field in the hard basal plane, the magnetic properties are qualitatively reminiscent of the situation for field parallel to the easy [001] axis. However, closer inspection reveals more complex behavior. As shown in Fig. 6(a) for field along [100], the differential and the ac susceptibility exhibit four distinct anomalies as a function of increasing field instead of two. Namely, the maximum at H_1 is followed by a weak kink, denoted at H_2 , and a shoulder,

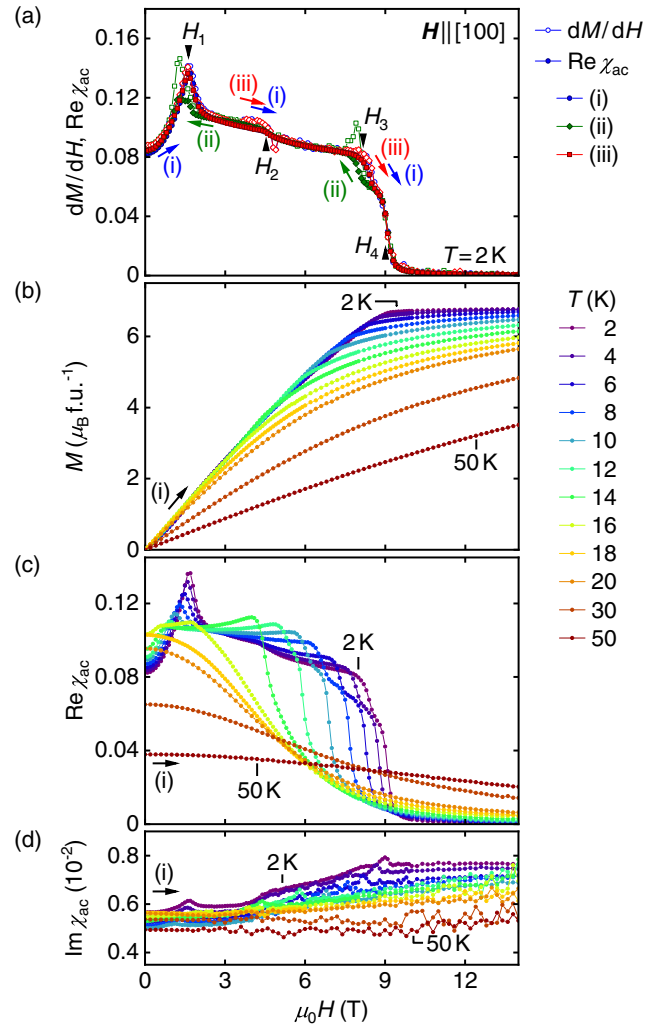


FIG. 6. Field dependence of the magnetic properties of EuPtSi_3 for field parallel to [100]. (a) Differential susceptibility calculated from the measured magnetization, dM/dH (open symbols), and real part of the ac susceptibility, $\text{Re } \chi_{\text{ac}}$ (solid symbols), at 2 K for different field histories. [(b)–(d)] Magnetization as well as real and imaginary part of the ac susceptibility for different temperatures.

denoted H_3 , before the field-polarized regime is entered above the point of inflection at H_4 .

Essentially identical behavior is observed for both histories measured under increasing field, (i) and (iii), while decreasing field, history (ii), reveals pronounced hysteresis at H_1 , from H_1 to H_2 , and around H_3 . For the construction of the magnetic phase diagrams, the transition H_3 is defined as the center of the hysteresis. Discrepancies between the differential susceptibility, dM/dH , and the real part of the ac susceptibility $\text{Re } \chi_{\text{ac}}$ accompany the phase transitions at H_1 , H_2 , and H_3 , being most pronounced under decreasing field. Consistent with the results for field applied along the easy [001] axis, both the history dependence and the discrepancies between differential and ac susceptibility suggest the presence of mesoscale magnetic textures and the importance of slow reorientation processes in EuPtSi_3 .

With increasing temperature, the transition fields shift to lower values, as illustrated in Figs. 6(b)–6(d) where data are

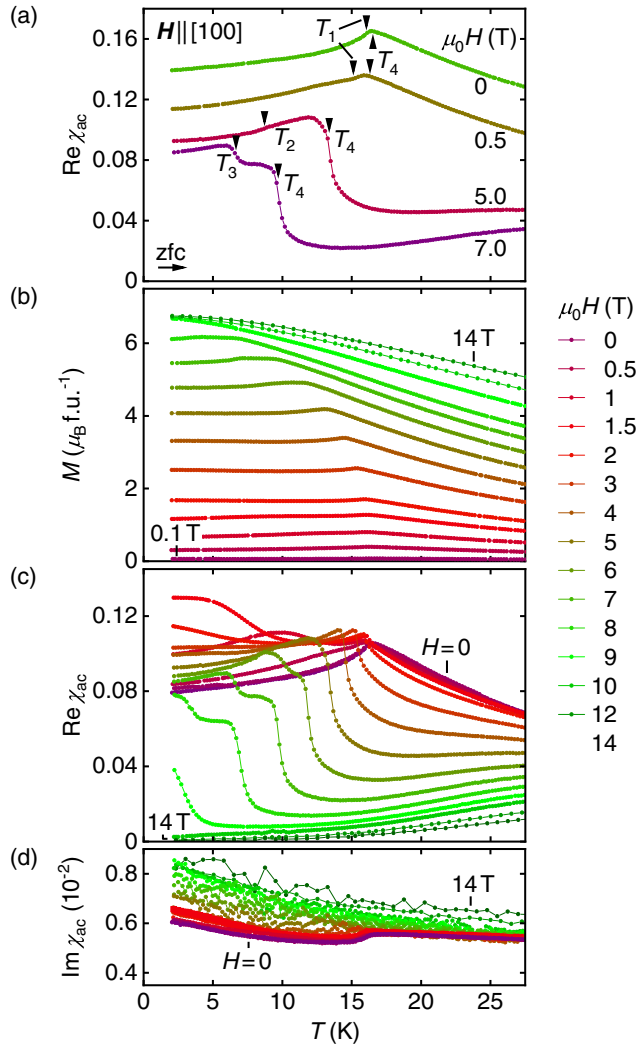


FIG. 7. Temperature dependence of the magnetic properties of EuPtSi₃ for field parallel to [100]. (a) Real part of the ac susceptibility for selected fields measured after zero-field cooling (zfc). Data are offset for clarity. [(b)–(d)] Magnetization as well as real and imaginary part of the ac susceptibility for a large number of fields up to 14 T.

shown for increasing fields after zero-field cooling. The signatures characteristic of H_2 and H_3 vanish at lower temperatures than H_1 and H_4 , enclosing distinct phase pockets in the magnetic phase diagram, as highlighted below.

As a function of temperature, four signatures may be distinguished, as shown in Fig. 7(a) for four field values with typical characteristics. In analogy to the corresponding anomalies in the field dependence of the susceptibility, these temperatures are referred to as T_1 , T_2 , T_3 , and T_4 . Their evolution for a large number of field values is illustrated in Figs. 7(b)–7(d). Akin to the behavior for field parallel to [001], a shallow maximum is observed in the ac susceptibility at temperatures well above T_N and associated with the crossover between the field-polarized and the paramagnetic regime (not shown).

The behavior for field along [110], shown in Fig. 8(a), is highly reminiscent of the situation for field along [100]

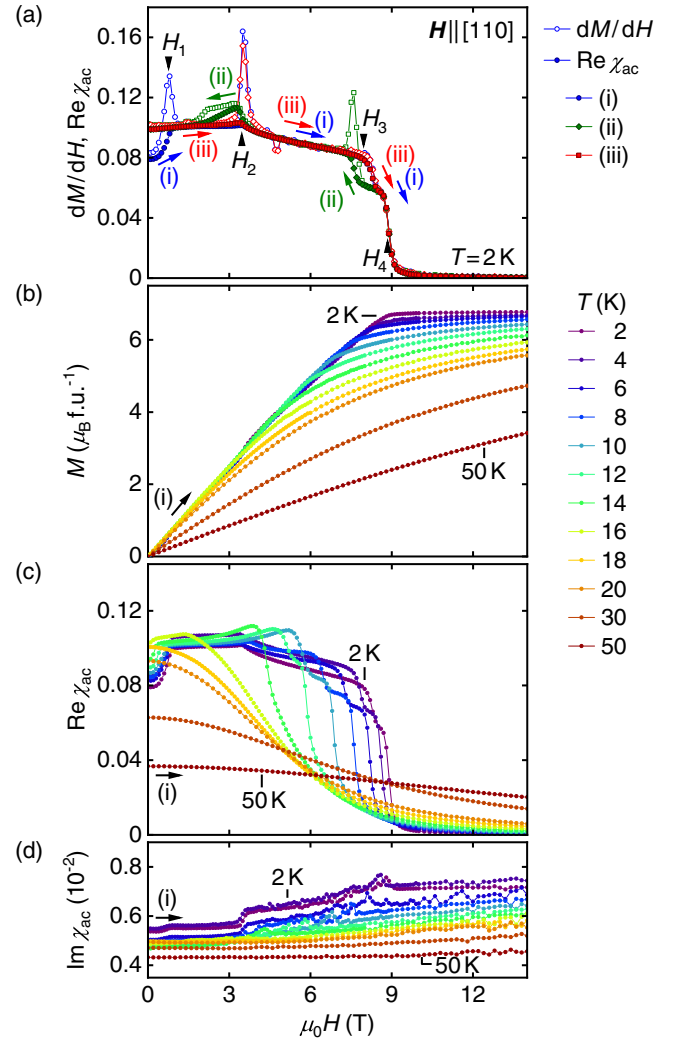


FIG. 8. Field dependence of the magnetic properties of EuPtSi₃ for field parallel to [110]. (a) Differential susceptibility calculated from the measured magnetization, dM/dH (open symbols), and real part of the ac susceptibility, $\text{Re } \chi_{ac}$ (solid symbols), at 2 K for different field histories. [(b)–(d)] Magnetization as well as real and imaginary part of the ac susceptibility for different temperatures.

with four distinct anomalies being observed as a function of increasing field. Both the hysteresis between different field histories and the discrepancy between differential and ac susceptibility are more pronounced than for field parallel to [100], as elaborated on in the following.

The signatures associated with H_1 are observed only after zero-field cooling, referred to as history (i), in contrast to the other field directions studied. Even for this field history, the maximum in the differential susceptibility at H_1 is not tracked by the ac susceptibility. Such a dependence may hint at a long-wavelength modulated magnetic texture for which the projection of the propagation direction into the basal plane is oriented along one of the $\langle 110 \rangle$ axes, in analogy to the helical-to-conical transition for magnetic field along an easy axis in cubic chiral magnets [49]. At H_2 a sharp peak in the differential susceptibility under increasing field, histories (i) and (iii), compares with a kink in the ac suscep-

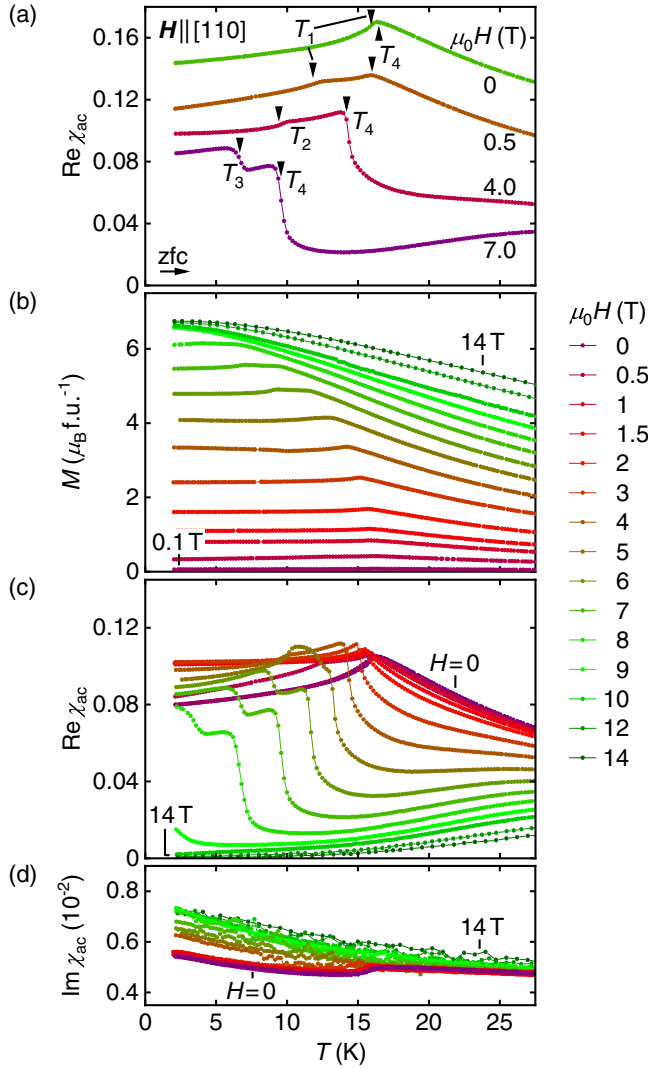


FIG. 9. Temperature dependence of the magnetic properties of EuPtSi₃ for field parallel to [110]. (a) Real part of the ac susceptibility for selected fields measured after zero-field cooling (zfc). Data are offset for clarity. [(b)–(d)] Magnetization as well as real and imaginary part of the ac susceptibility for a large number of fields up to 14 T.

tibility that resembles the data for field along [100]. Under decreasing field, history (ii), a broad asymmetric maximum is observed at slightly lower field values in both differential and ac susceptibility. The hysteric loop around H_3 is wider than for field along [100] and under decreasing field, history (ii), at its low-field boundary a peak is observed in the differential susceptibility that is not tracked by the ac susceptibility.

The evolution of the anomalies with increasing temperature, shown in Figs. 8(b)–8(d), as well as the magnetic properties as a function of temperature, shown in Fig. 9, are highly reminiscent of the evolution for field parallel to [100]. Consistent with the data as a function of field, dependence on the temperature and field history is observed in particular in scans at fields below H_1 (not shown). All things considered, however, the magnetic phase diagrams for fields in the

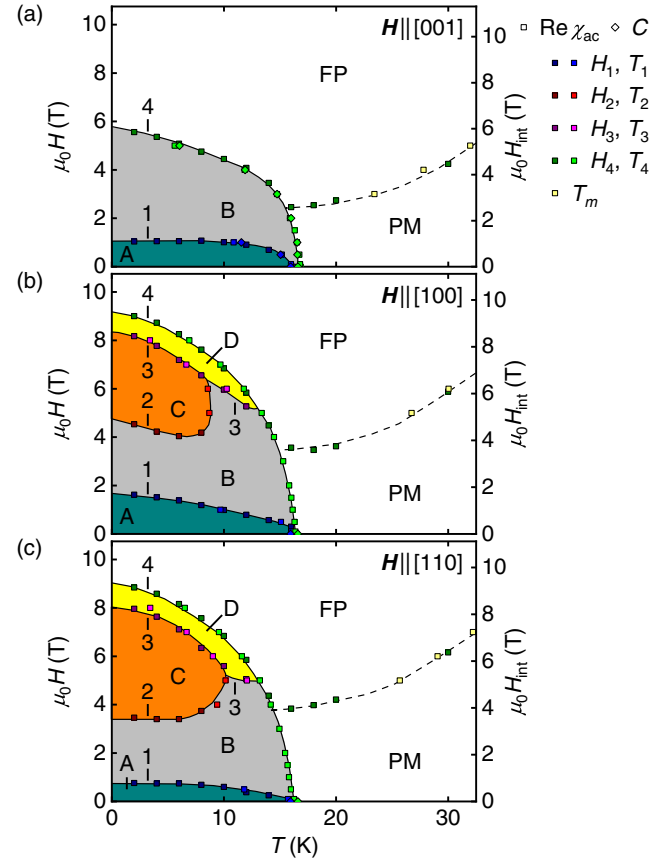


FIG. 10. Magnetic phase diagrams of EuPtSi₃ for field along [001], [100], and [110] after zero-field cooling. Data inferred from measurements as a function of field and temperature are shown in dark and light colors, respectively. Paramagnetic (PM) and field-polarized (FP) regimes as well as four ordered phases, labeled A through D, are distinguished. Arabic numbers denote transition lines as defined by the transition fields and temperatures denoted with that number.

tetragonal basal plane turn out to be essentially isotropic with a slightly harder [100] axis.

D. Magnetic phase diagrams

The magnetic phase diagrams of EuPtSi₃ for the three field directions studied are shown in Fig. 10. The ordinate on the right-hand side displays an estimate of the internal field values H_{int} when correcting for demagnetization effects [53,54]. Taking together the data for all field directions, the magnetic phase diagrams feature four different phases, labeled A through D, as well as the paramagnetic state (PM) at high temperatures and a field-polarized regime (FP) at high fields. For zero magnetic field and decreasing temperature, the paramagnetic state undergoes a transition to phase B at $T_N = T_4(H = 0) = 17$ K, followed by a transition to phase A at $T_{N2} = T_1(H = 0) = 16$ K.

Under increasing magnetic field along [001], the transition between phases A and B occurs at H_1 , followed by a transition from phase B to the field-polarized regime at H_4 . The transition fields emanate from T_{N2} and T_N , respectively, and increase monotonically with decreasing temperature. This

phase diagram is consistent with Ref. [33], apart from two noticeable exceptions. First, the presence of phase B in zero field was not addressed. Second, for the transition line denoted (1) a slightly convex shape was reported, implying reentrant behavior. No such behavior is observed in our study.

For magnetic fields in the basal plane, two additional states emerge, labeled C and D, before the field-polarized regime is entered. Hysteresis under increasing and decreasing fields is observed at the transitions between phases B and C, denoted transition line (2), as well as C and D, denoted transition line (3). For field along [110], the hysteresis is more pronounced and, perhaps most notably, signatures associated with phase A are observed after zero-field cooling only. These hysteretic effects as well as the discrepancies between the differential and the ac susceptibility consistently suggest the presence of mesoscale textures of a long-wavelength modulated magnetic state with phase transitions that are governed by slow reorientation processes. The zero-temperature extrapolation of the transition fields H_1 , H_2 , H_3 , and H_4 along [110] are a few hundred millitesla smaller than for field along [100], characteristic of weak in-plane anisotropy featuring [100] as the hardest axis.

E. Neutron diffraction

Microscopic information on the magnetic structure of EuPtSi₃ may be inferred from neutron diffraction. As shown in Fig. 11, the powder diffractogram at room temperature is consistent with a phase-pure sample crystallizing in space group $I4mm$. The structural parameters obtained by means of a Rietveld analysis are summarized in Table I, establishing excellent agreement between values extracted from neutron and x-ray diffraction, cf. Fig. 1(a). Refinements considering Pt–Si mixed occupations on sites Pt1, Si1, and Si2 yield an upper limit for Pt–Si antisite disorder of less than 3%.

As a function of decreasing temperature, the crystal structure stays unchanged with the lattice constants decreasing by up to 0.2%. As shown in Fig. 11(a), below $T_N = 17$ K additional intensity maxima emerge that are attributed to the onset of long-range magnetic order. The present data focus on low temperatures in zero field, corresponding to phase A in the magnetic phase diagram. In order to obtain an estimate of the pure magnetic contribution, the room-temperature diffractogram is subtracted from the low-temperature data. As highlighted in Fig. 11(b), the most prominent contribution is a characteristic triplet around $2\Theta = 9$ deg, denoted (I), (II), and (III).

The description of these maxima requires the superposition of at least two ordering vectors, notably in the conventional unit cell the commensurate wave vector with $\mathbf{k}_{15} = (001)$ and an incommensurate wave vector $\mathbf{k}_{10} = (00z)$ with $z = 1.081$ r.l.u. (reciprocal lattice units) at 4 K. Therefore, the triplet may be indexed as $(002) - \mathbf{k}_{10}$, $(000) + \mathbf{k}_{15}$, and $(000) + \mathbf{k}_{10}$. With increasing temperature, z increases to 1.088 r.l.u. at 13 K, corresponding to a decrease of the real-space periodicity from 121 Å to 111 Å. As shown in Fig. 11(c), a Rietveld refinement based on such antiferromagnetic order with multiple ordering vectors is in very good agreement with the diffraction pattern up to high scattering angles. Here, intervals of 2Θ were omitted (excl.) that were dominated by scattering from the sample

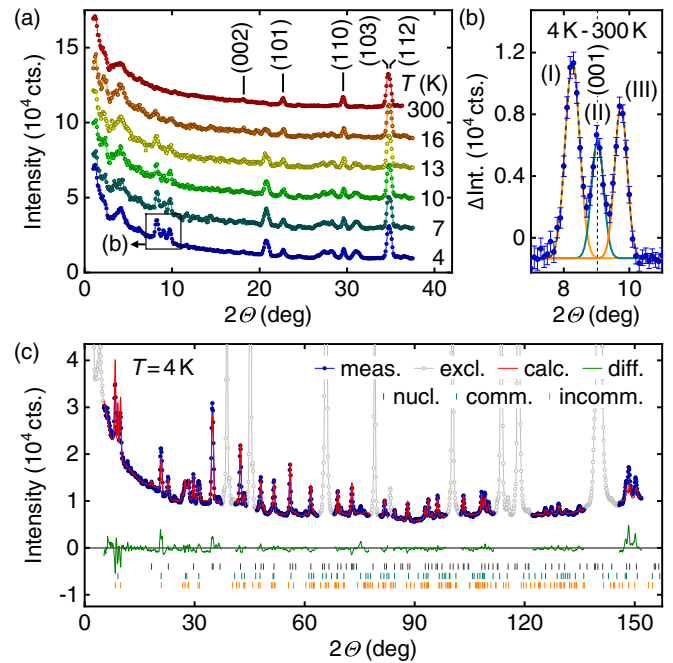


FIG. 11. Neutron powder diffraction on EuPtSi₃. (a) Diffraction patterns for different temperatures. Below the onset of magnetic order additional maxima emerge. Data are offset for clarity. (b) Enlarged view of the triplet structure around $2\Theta = 9$ deg where an estimate of the pure magnetic contribution is obtained by subtraction of high-temperature data. Solid lines are Gaussian fits, the dashed line represents the sum of the three Gaussians. (c) Rietveld refinement of low-temperature data. Measured data (meas.), calculations (calc.), and their difference (diff.) are distinguished. Angles dominated by scattering from the sample environment were excluded (excl.). Short-vertical lines indicate maxima related to the crystalline structure (nucl.) and the magnetic ordering vectors (comm., incomm.).

environment. Incommensurate order in phase A contrasts the findings of Kumar and colleagues, which proposed a commensurate equal-moment antiferromagnetic structure, based on specific heat measurements and Mössbauer spectroscopy [33].

Unfortunately, the present data do not allow to determine the character of the incommensurate order unambiguously. The refinement in Fig. 11(c) assumes an incommensurate spin density wave with moments along the edge of the basal plane, but calculations assuming Néel-type cycloids and Bloch-type helices describe the data equally well (not shown). Moreover, a search for incommensurate ordering vectors was carried out in the basal plane of the tetragonal crystal structure. When assuming $\mathbf{k}_1 = (y + x, 0, y - x)$ or $\mathbf{k}_3 = (x + y, x + y, 2x)$, the fits converge at ordering vectors that correspond to \mathbf{k}_{15} and \mathbf{k}_{10} on the resolution of our study. Consequently, if there is a modulation within the basal plane of EuPtSi₃ in phase A, it will be either weak or its wavelength will be very long. No hints for a reduction of the space group symmetry of the crystal structure were observed, such as a loss of the centering translation.

Complementary single-crystal neutron diffraction data are presented in Fig. 12 in the form of two scans along (00L) at

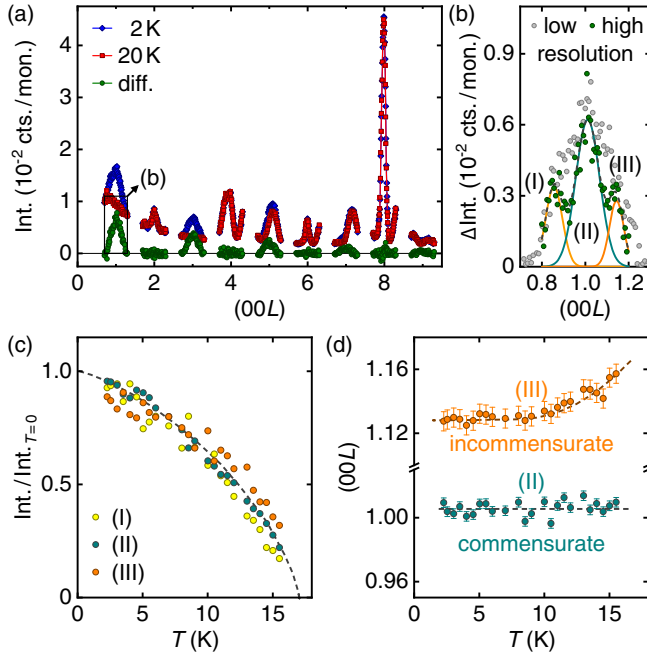


FIG. 12. Single-crystal neutron diffraction on EuPtSi_3 . (a) Intensity scans along (00L) for different temperatures. Subtracting high-temperature data yields an estimate for the magnetic contribution at low temperatures (diff.). (b) Enlarged view around the magnetic (001) intensity maximum. A triplet structure is clearly identified in high-resolution data. Solid lines are Gaussian fits, the dashed line represents the sum of the three Gaussians. [(c),(d)] Temperature dependence of the intensity and the position of maxima around (001).

temperatures above and below the onset of magnetic order. In space group $I4mm$, intensity is expected only at reflections (hkl) where the sum of h , k , and l is even, in excellent agreement with high-temperature data in neutron and x-ray powder diffraction. At low temperatures, the single-crystal diffraction data exhibit additional maxima at positions with odd values of L . These maxima may be resolved best when considering the difference (diff.) of the low-temperature and high-temperature data and decrease in intensity with increasing L . Additional contributions independent of temperature, for instance near (005) or (007), appear to be spurious as they may be attributed to scattering from the sample environment.

As shown in Fig. 12(b), only a single broad maximum is resolved around (001) on HEiDi in standard configuration (gray symbols). Placing an α_2 Soller collimator with a horizontal beam divergence of $15'$ in front of the sample allows us to resolve a triplet structure. The experimental data may be fitted with three Gaussians, yielding peak positions of 0.881 r.l.u., 1.009 r.l.u., and 1.128 r.l.u., respectively. This splitting is qualitatively consistent though larger than the splitting observed in the powder diffraction data, which may be attributed to the nonoptimal alignment of the resolution ellipsoids in our single-crystal diffraction experiment.

The integrated intensities of the three Gaussian maxima decrease simultaneously as a function of increasing temperature, as shown in Fig. 12(c). This behavior clearly establishes the origin of the scattering as magnetic. However, the data

TABLE II. Dzyaloshinskii-Moriya vectors as constrained by the crystal structure of EuPtSi_3 in space group $I4mm$. Along specific types of crystallographic directions, for an europium moment at position $\mathbf{R}_i = (0, 0, 0)$ low-order nearest-neighbor europium moments at positions \mathbf{R}_j are considered, where a and c are the tetragonal lattice constants. Applying the Moriya rules [11], allowed orientations of the Dzyaloshinskii-Moriya vector \mathbf{D}_{ij} are inferred, thereby determining the favored type of long-wavelength modulation.

Direction	\mathbf{R}_j	\mathbf{D}_{ij}	Modulation
$\langle 100 \rangle$	$(a, 0, 0)$	$\pm(0, 1, 0)$	Néel-type
$\langle 111 \rangle$	$(a/2, a/2, c/2)$	$\pm(1, \bar{1}, 0)$	Néel-type
$\langle 110 \rangle$	$(a, a, 0)$	$\pm(1, \bar{1}, 0)$	Néel-type
$\langle 001 \rangle$	$(0, 0, c)$	$(0, 0, 0)$	None

available do not allow us to discriminate whether the intensity vanishes at T_{N1} or T_N . As depicted in Fig. 12(d), the position of the central maximum of the triplet remains unchanged as a function of increasing temperature, consistent with a commensurate ordering vector, while for the incommensurate maxima the separation away from (001) increases from 0.128 r.l.u. at 2 K to 0.157 r.l.u. at 15.5 K.

F. Magnetic structure

The crystal structure of EuPtSi_3 sets the stage for potential magnetic structures. Due to the lack of inversion symmetry, neighboring magnetic moments, \mathbf{S}_i and \mathbf{S}_j , may be subject to the Dzyaloshinskii-Moriya interaction $\mathbf{D}_{ij} \cdot (\mathbf{S}_i \times \mathbf{S}_j)$ with the Dzyaloshinskii-Moriya vectors \mathbf{D}_{ij} [10–12]. The corresponding energy is minimized when \mathbf{S}_i , \mathbf{S}_j , and \mathbf{D}_{ij} form an orthogonal trihedron. In combination with interactions favoring collinear alignment, such as ferromagnetic or antiferromagnetic exchange interactions, the moments may form a long-wavelength modulated structure in the plane perpendicular to \mathbf{D}_{ij} .

The space group $I4mm$ constrains possible Dzyaloshinskii-Moriya vectors \mathbf{D}_{ij} , as inferred from the Moriya rules [11] and summarized in Table II. For moments neighboring along the basal edges $\langle 100 \rangle$, the tetragonal diagonals $\langle 111 \rangle$, or the basal face diagonals $\langle 110 \rangle$, the Dzyaloshinskii-Moriya vectors are perpendicular to the line connecting the moments. Thus, when considering long-wavelength magnetic modulations, Néel-type cycloids are favored over Bloch-type helices. As Dzyaloshinskii-Moriya vectors with opposite sign are mapped onto each other by mirror symmetries of space group $I4mm$, the magnetic modulation is expected to inherit this achirality. For moments neighboring along $\langle 001 \rangle$, the Dzyaloshinskii-Moriya vector vanishes. As an additional note, the space groups $I4mm$ belongs to point group C_{4v} , for which magnetic vortices, so-called skyrmions, were predicted that are based on Néel-type cycloids [55–57].

In combination with the results of the bulk measurements and neutron scattering, these considerations permit us to identify key characteristics of the magnetic order in EuPtSi_3 . In zero magnetic field at low temperatures, namely in phase A, our data are consistent with local-moment antiferromagnetism of the europium moments that is modulated on a length scale

of ~ 100 Å in terms of a Néel-type cycloidal. For this conjecture, the following aspects are crucial.

First, the crystal structure belongs to space group $I4mm$, which lacks inversion symmetry and therefore may support long-wavelength magnetic modulations stabilized by means of Dzyaloshinskii-Moriya interactions, favoring Néel-type cycloidals rather than Bloch-type helices. Second, magnetization and specific heat data indicate that the magnetism is carried by localized Eu^{2+} moments with quenched orbital momentum and equal size on all sites. Third, the differential and the ac susceptibility exhibit a pronounced history dependence, in particular for field along the basal face diagonals $\langle 110 \rangle$, suggesting the presence of mesoscale magnetic domains. Fourth, neutron scattering is in agreement with commensurate antiferromagnetic order that is superimposed by a long-wavelength incommensurate magnetic texture propagating along $\langle 001 \rangle$. Fifth, taken together, the two previous aspects suggest either (i) propagation along $\langle 001 \rangle$ with domains featuring projections of moments parallel to $\langle 110 \rangle$ or (ii) propagation along directions slightly tilted away from $\langle 001 \rangle$ toward $\langle 110 \rangle$ such that the peak splitting is well below the resolution of our neutron scattering study.

IV. CONCLUSIONS

In summary, our study reported the growth of a single crystal of EuPtSi_3 , crystallizing in the noncentrosymmetric tetragonal space group $I4mm$, by means of the optical floating-zone technique. This single crystal was studied by means of magnetization, ac susceptibility, and specific heat as well as powder and single-crystal neutron diffraction. The magnetization and specific heat are characteristic of localized Eu^{2+} moments. As a function of decreasing temperature, two narrowly separated magnetic phase transitions are observed at $T_N = 17$ K and $T_{N2} = 16$ K. Under applied magnetic field along the easy $[001]$ axis, two phases are observed for which the phase transition lines connect with T_N and T_{N1} . At low temperatures, the field-polarized state is entered above 5.5 T. Under applied field in the hard basal plane, two additional

phases emerge in larger fields. The in-plane anisotropy is weak, where $[100]$ represents the hardest axis, with the field-polarized state at low temperatures forming above 9.0 T and 8.8 T for field along $[100]$ and $[110]$, respectively.

Neutron scattering in zero field at low temperatures exhibits a splitting of magnetic intensity maxima, characteristic of a long-wavelength modulated antiferromagnetic texture, most likely in the form of a Néel-type cycloid. These findings highlight that the quenched orbital momentum of intermetallic europium compounds leads to relatively weak spin-orbit coupling, making them prime candidates for long-wavelength magnetic modulations, in particular when combined with crystal structures lacking inversion symmetry, thus permitting Dzyaloshinskii-Moriya interactions.

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